

PROTECTION PRODUCTS

Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (tp = 8/20μs)	P_{pk}	450	Watts
Peak Pulse Current (tp = 8/20μs)	I_{pp}	25	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	25 15	kV
Operating Temperature	T_J	-55 to +125	°C
Storage Temperature	T_{STG}	-55 to +150	°C

Electrical Characteristics (T=25°C)

RClamp2504N						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V_{RWM}				2.5	V
Punch-Through Voltage	V_{PT}	$I_{PT} = 2\mu A$	2.7			V
Snap-Back Voltage	V_{SB}	$I_{SB} = 50mA$	2.0			V
Reverse Leakage Current	I_R	$V_{RWM} = 2.5V, T=25^\circ C$			0.5	μA
Clamping Voltage	V_C	$I_{pp} = 1A, t_p = 8/20\mu s$			4.5	V
Clamping Voltage	V_C	$I_{pp} = 10A, t_p = 8/20\mu s$			7.5	V
Clamping Voltage	V_C	$I_{pp} = 25A, t_p = 8/20\mu s$			15	V
Junction Capacitance	C_j	Between I/O pins and Ground $V_R = 0V, f = 1MHz$		3.8	5	pF
		Between I/O pins $V_R = 0V, f = 1MHz$		2.0		pF

Note 1: I/O pins are pin 1, 3, 7, and 9

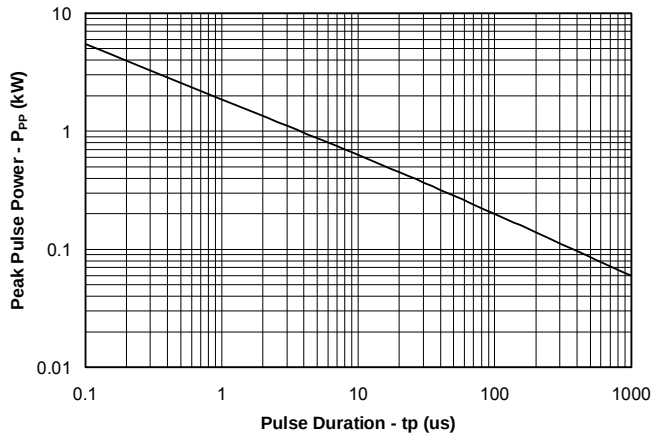
PROTECTION PRODUCTS

RClamp3304N						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V_{RWM}				3.3	V
Punch-Through Voltage	V_{PT}	$I_{PT} = 5\mu A$	3.5			V
Snap-Back Voltage	V_{SB}	$I_{SB} = 50mA$	2.8			V
Reverse Leakage Current	I_R	$V_{RWM} = 3.3V, T=25^\circ C$			0.5	μA
Clamping Voltage	V_C	$I_{PP} = 1A, t_p = 8/20\mu s$			5.5	V
Clamping Voltage	V_C	$I_{PP} = 10A, t_p = 8/20\mu s$			10.5	V
Clamping Voltage	V_C	$I_{PP} = 25A, t_p = 8/20\mu s$			18	V
Junction Capacitance	C_j	Between I/O pins and Ground $V_R = 0V, f = 1MHz$		3.8	5	pF
		Between I/O pins $V_R = 0V, f = 1MHz$		2.0		pF

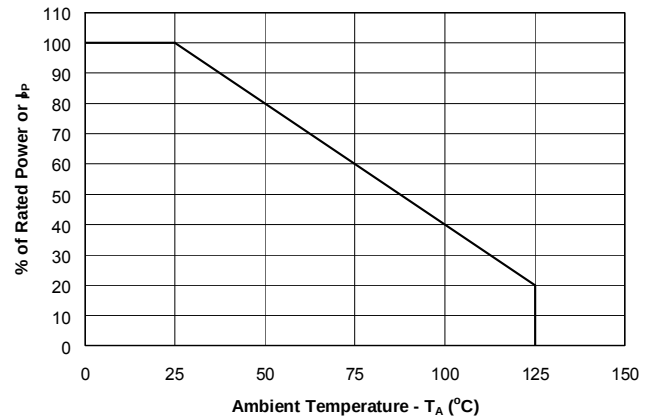
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Typical Characteristics

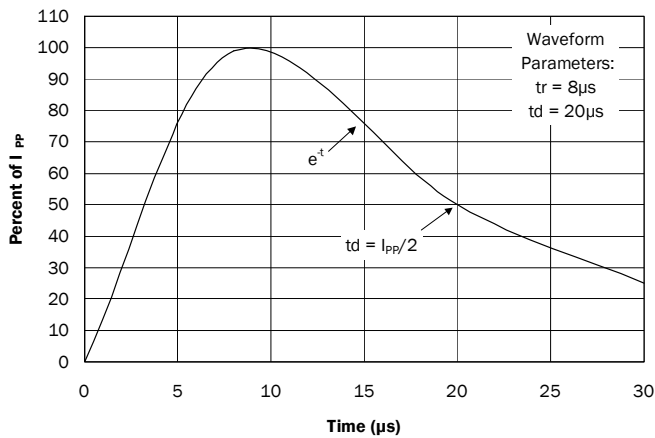
Non-Repetitive Peak Pulse Power vs. Pulse Time



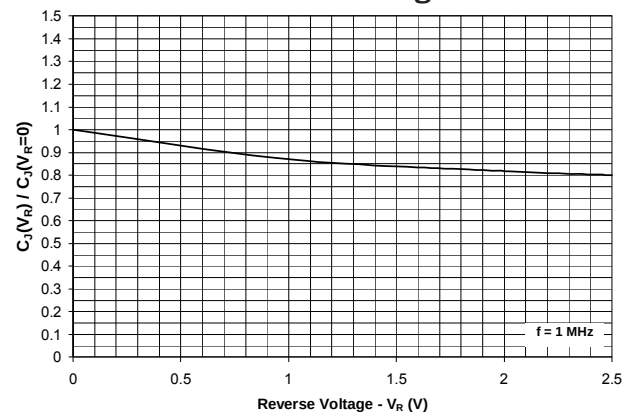
Power Derating Curve



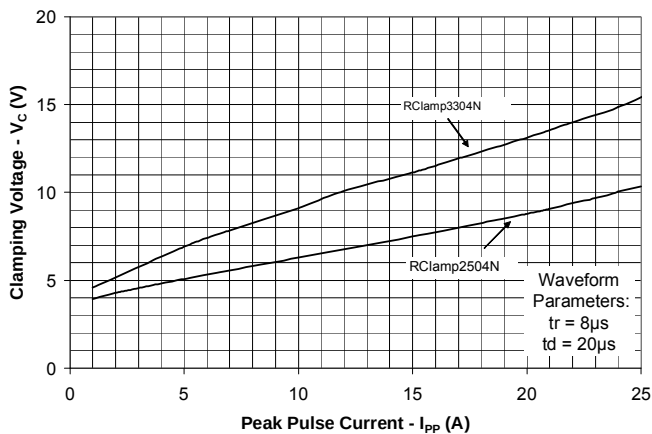
Pulse Waveform



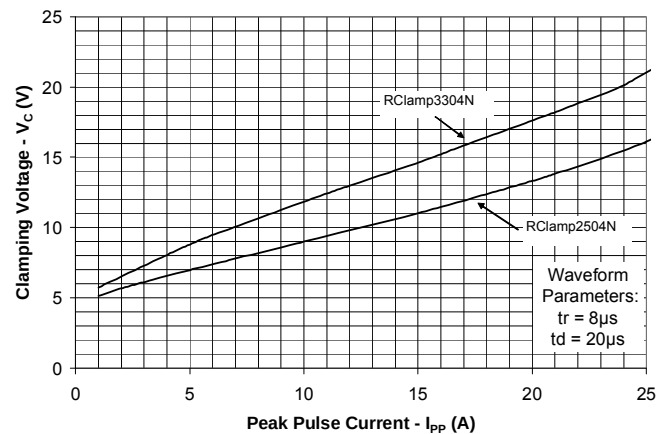
Normalized Junction Capacitance vs. Reverse Voltage



**Clamping Voltage vs. Peak Pulse Current
I/O to GND**



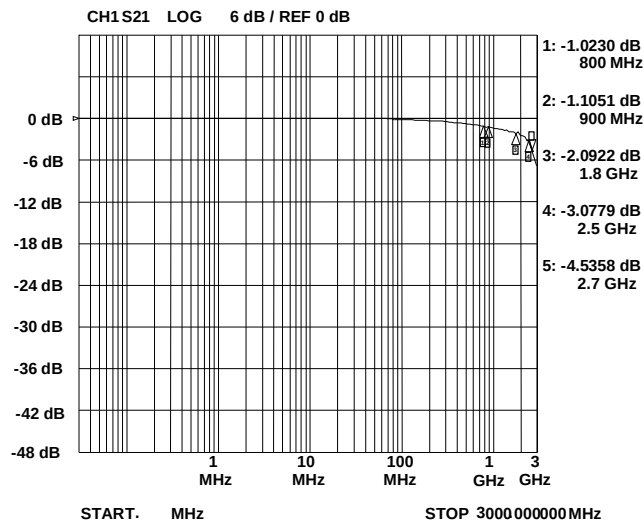
**Clamping Voltage vs. Peak Pulse Current
I/O to I/O**



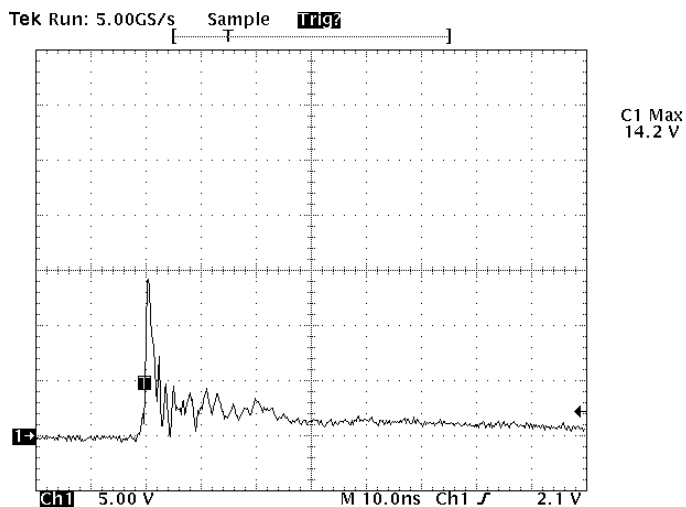
PROTECTION PRODUCTS

Typical Characteristics

Insertion Loss S21 (I/O to Ground)



ESD Clamping
(8kV Contact per IEC 61000-4-2)



Note: Data is taken with a 10x attenuator

PROTECTION PRODUCTS

Applications Information

Device Connection Options for Protection of Four High-Speed Data Lines

These devices are designed to protect low voltage data lines operating at 2.5 volts or 3.3 volts. When the voltage on the protected line exceeds the reference voltage the steering diodes are forward biased, conducting the transient current away from the sensitive circuitry.

Data lines are connected at pins 1, 3, 7 and 9. The center pin should be connected directly to a ground plane. The path length is kept as short as possible to minimize parasitic inductance. Pins 2, 4, 6, 8, and 10 are not connected.

Note that pin 5 is connected internally to the cathode of the low voltage TVS. It is not recommended that these pins be directly connected to a DC source greater than the snap-back voltage (V_{SB}) as the device can latch on as described below.

EPD TVS Characteristics

These devices are constructed using Semtech's proprietary EPD technology. By utilizing the EPD technology, the RClamp2504N and RClamp3304N can effectively operate at 2.5V and 3.3V respectively while maintaining excellent electrical characteristics.

The EPD TVS employs a complex npnp structure in contrast to the pn structure normally found in traditional silicon-avalanche TVS diodes. Since the EPD TVS devices use a 4-layer structure, they exhibit a slightly different IV characteristic curve when compared to conventional devices. During normal operation, the device represents a high-impedance to the circuit up to the device working voltage (V_{RWM}). During an ESD event, the device will begin to conduct and will enter a low impedance state when the punch through voltage (V_{PT}) is exceeded. Unlike a conventional device, the low voltage TVS will exhibit a slight negative resistance characteristic as it conducts current. This characteristic aids in lowering the clamping voltage of the device, but must be considered in applications where DC voltages are present.

When the TVS is conducting current, it will exhibit a slight "snap-back" or negative resistance characteristics due to its structure. This point is

Circuit Diagram

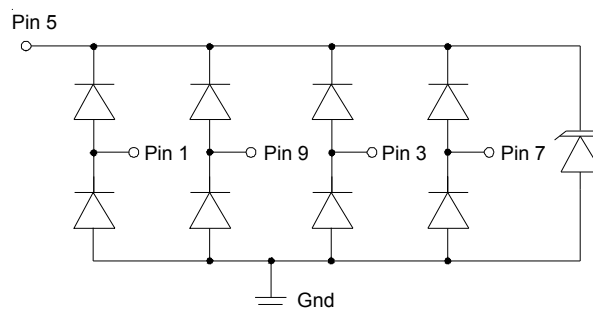
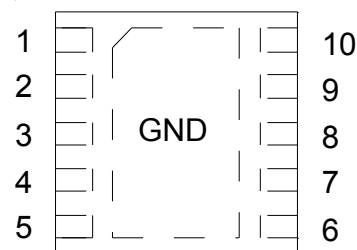


Figure 1. Pin Configuration (Top Side View)

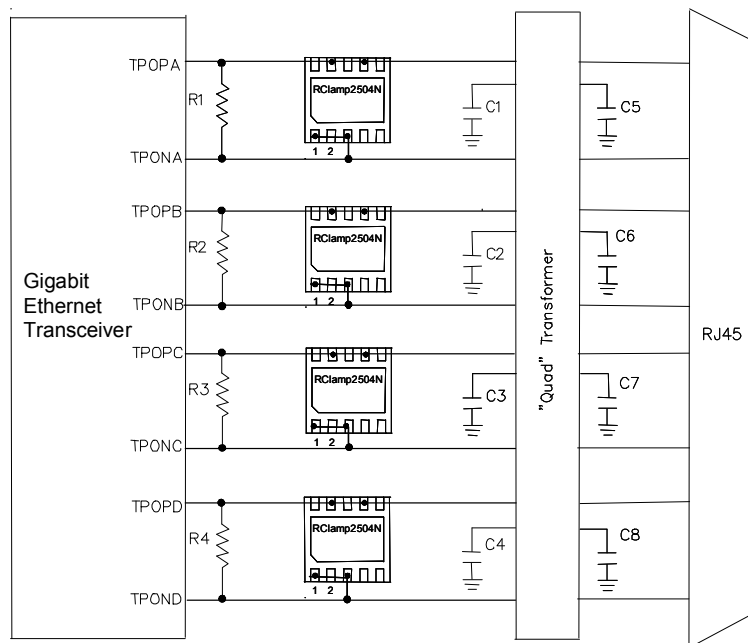


Pin	Identification
1, 3, 7, 9	Input/Output Lines
2, 4, 6, 8, 10	No Connect
5	No Connect (Do not connect this pin to a DC supply)
Center Tab	Ground

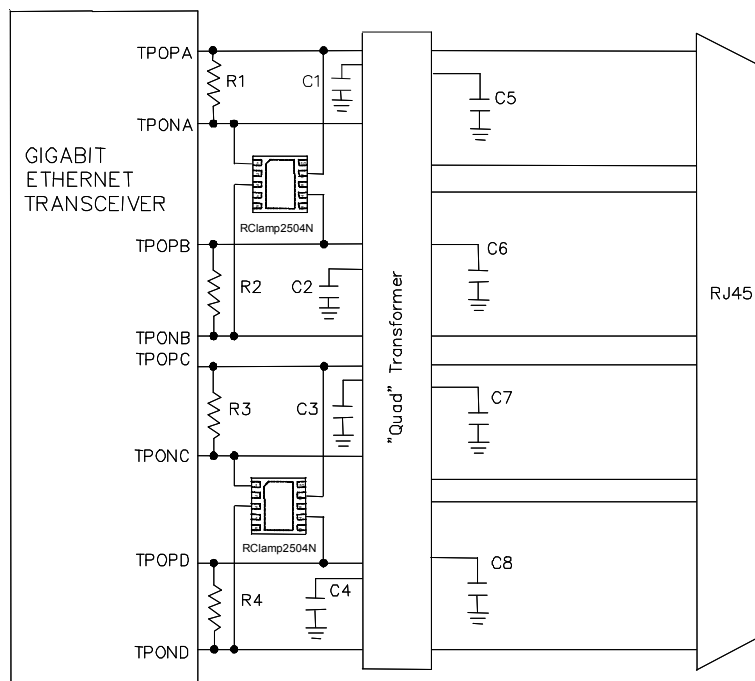
defined on the curve by the snap-back voltage (V_{SB}) and snap-back current (I_{SB}). To return to a non-conducting state, the current through the device must fall below the I_{SB} (approximately $<50\text{mA}$) and the voltage must fall below the V_{SB} (normally 2.8 volts for a 3.3V device). If a 3.3V TVS is connected to 3.3V DC source, it will never fall below the snap-back voltage of 2.8V and will therefore stay in a conducting state.

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Applications Information



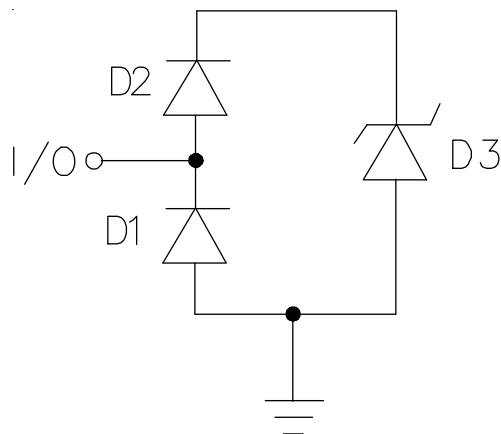
**Schematic Diagram for Gigabit Ethernet Telcordia GR-1089 Intra-Building Protection
(PHY Operating Temp $\leq 90^{\circ}\text{C}$)**



Schematic Diagram for Gigabit Ethernet ESD Protection

PROTECTION PRODUCTS

Applications Information - Spice Model

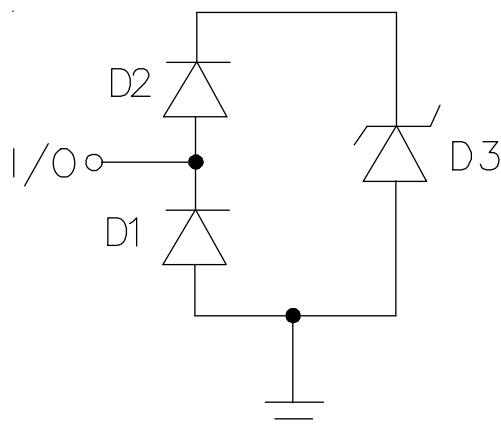


RClamp2504N Spice Model

RClamp2504N Spice Parameters				
Parameter	Unit	D1 (LCRD)	D2 (LCRD)	D3 (TVS)
IS	Amp	1E-20	1E-20	1.66E-13
BV	Volt	100	100	2.89
VJ	Volt	0.63	0.59	0.53
RS	Ohm	0.138	0.241	0.06
IBV	Amp	1E-3	1E-3	1E-3
CJO	Farad	1.5E-12	1.5E-12	288E-12
TT	sec	2.541E-9	2.541E-9	2.541E-9
M	—	0.01	0.01	0.17
N	—	1.1	1.1	1.1
EG	eV	1.11	1.11	1.11

PROTECTION PRODUCTS

Applications Information - Spice Model

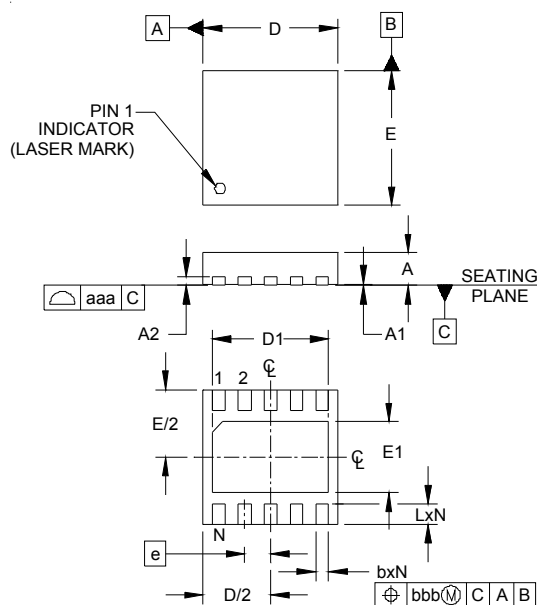


RClamp3304N Spice Model

RClamp3304N Spice Parameters				
Parameter	Unit	D1 (LCRD)	D2 (LCRD)	D3 (TVS)
IS	Amp	1E-20	1E-20	1.66E-13
BV	Volt	100	100	3.55
VJ	Volt	0.62	0.59	0.6
RS	Ohm	0.138	0.241	0.182
IBV	Amp	1E-3	1E-3	1E-3
CJO	Farad	1.5E-12	1.5E-12	253E-12
TT	sec	2.541E-9	2.541E-9	2.541E-9
M	—	0.01	0.01	0.205
N	—	1.1	1.1	1.1
EG	eV	1.11	1.11	1.11

PROTECTION PRODUCTS

Outline Drawing - SLP2626P10

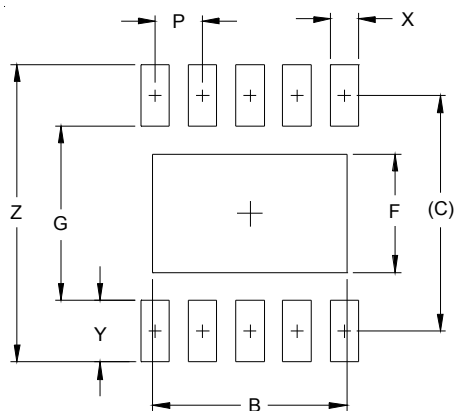


DIM	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	.020	.024	.026	0.50	0.60	0.65
A1	.000	.001	.002	0.00	0.03	0.05
A2		(.007)			(0.17)	
b	.007	.010	.012	0.20	0.25	0.30
D	.098	.102	.106	2.50	2.60	2.70
D1	.079	.085	.089	2.00	2.15	2.25
E	.098	.102	.106	2.50	2.60	2.70
E1	.044	.050	.054	1.11	1.26	1.36
e		.020 BSC			0.50 BSC	
L	.011	.014	.016	0.30	0.35	0.40
N		10			10	
aaa		.003			0.08	
bbb		.004			0.10	

NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

Land Pattern - SLP2626P10



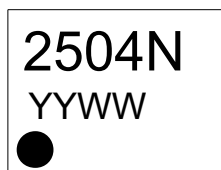
DIM	INCHES		MILLIMETERS	
B	.081		2.05	
C	.100		2.50	
F	.050		1.26	
G	.073		1.85	
P	.020		0.50	
X	.012		0.30	
Y	.025		0.65	
Z	.124		3.15	

NOTES:

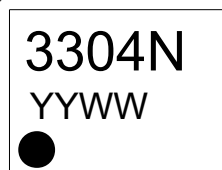
1. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.
CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR
COMPANY'S MANUFACTURING GUIDELINES ARE MET.

PROTECTION PRODUCTS

Marking



RClamp2504N



RClamp3304N

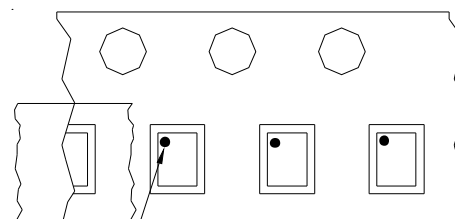
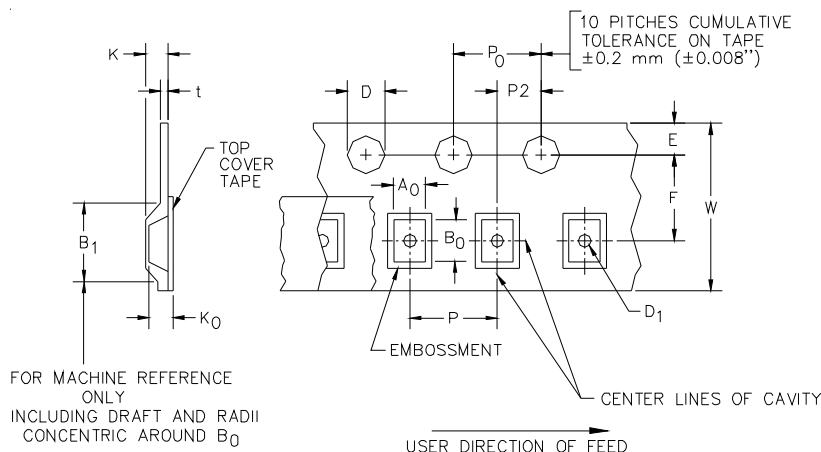
YYWW = Date Code

Ordering Information

Part Number	Working Voltage	Qty per Reel	Reel Size
RClamp2504N.TCT	2.5 Volts	3,000	7 Inch
RClamp3304N.TCT	3.3 Volts	3,000	7 Inch

RailClamp and RClamp are marks of Semtech Corporation

Tape and Reel Specification



Pin 1 Location

User Direction of feed

Device Orientation in Tape

A0	B0	K0
2.77 +/-0.10 mm	2.77 +/-0.10 mm	0.80 +/-0.10 mm

Tape Width	B, (Max)	D	D1	E	F	K (MAX)	P	P0	P2	T(MAX)	W
8 mm	4.2 mm (.165)	1.5 + 0.1 mm - 0.0 mm	1.0 mm ±0.05	1.750±.10 mm	3.5±0.05 mm	2.4 mm	4.0±0.1 mm	4.0±0.1 mm	2.0±0.05 mm	0.4 mm	8.0 mm + 0.3 mm - 0.1 mm

Contact Information

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